



# DMMT3906W

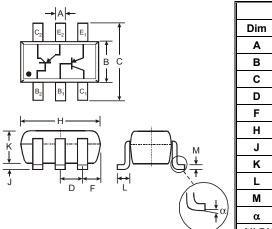
MATCHED PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

- Epitaxial Planar Die Construction
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% Matched Tolerance, h<sub>FE</sub>, V<sub>CE(SAT)</sub>, V<sub>BE(SAT)</sub>
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4 and 5)

## **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4B, See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.015 grams (approximate)



SOT-363							
Dim	Min Max						
Α	0.10	0.30					
в	1.15	1.35					
С	2.00	2.20					
D	0.65 N	ominal					
F	0.30	0.40					
н	1.80	2.20					
J	—	0.10					
к	0.90	1.00					
L	0.25	0.40					
м	0.10	0.25					
α	0°	8°					
All Dim	ensions	in mm					

Maximum Ratings	@T <sub>A</sub> = 25°C unless otherwise specified
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Characteristic	Symbol	Value	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage		V <sub>CEO</sub>	-40	V
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V
Collector Current - Continuous		Ιc	-200	mA
Power Dissipation	(Note 3)	Pd	200	mW
Thermal Resistance, Junction to Ambient	(Note 3)	$R_{ extsf{ heta}JA}$	625	°C/W
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 1. Built with adjacent die from a single wafer.

No purposefully added lead.

 Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



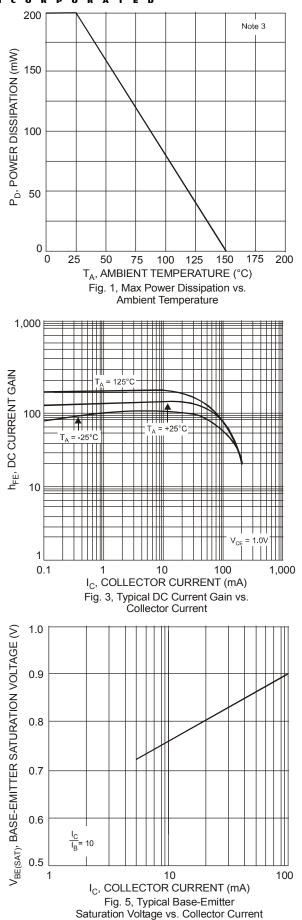
Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

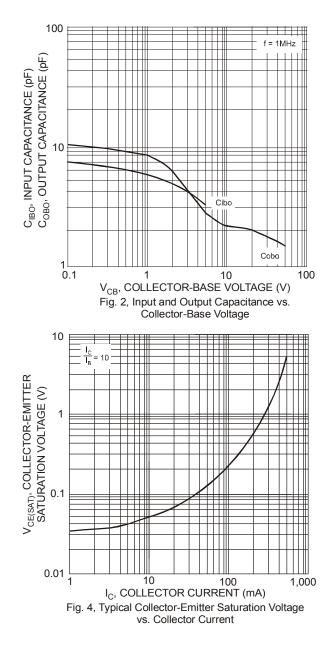
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	Symbol	Min	Max	Unit	Test Condition
			1	1	
	V <sub>(BR)CBO</sub>	-40	_		$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$
	$V_{(BR)CEO}$	-40		-	I <sub>C</sub> = -1.0mA, I <sub>B</sub> = 0
	$V_{(BR)EBO}$	-5.0		V	$I_{E} = -10\mu A$ , $I_{C} = 0$
	I <sub>CEX</sub>	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
	I <sub>BL</sub>	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
			•	•	• • • • • • • • • • • • • • • • • • •
		60			$I_{C} = -100 \mu A, V_{CE} = -1.0 V$
		80			$I_{C} = -1.0 \text{mA}, V_{CE} = -1.0 \text{V}$
(Note 7)	h <sub>FE</sub>	100	300		$I_{C} = -10 \text{mA}, V_{CE} = -1.0 \text{V}$
			—		$I_{C} = -50 \text{mA}, V_{CE} = -1.0 \text{V}$
		30	—		$I_{C} = -100 \text{mA}, V_{CE} = -1.0 \text{V}$
(Note 7)	Variant		-0.25	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA
(10007)	VCE(SAT)			•	I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA
(Note 7)	VRE(SAT)	-0.65		v	$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -1.0mA
(	. ,	_			I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA
	$\Delta V_{BE}$	_	-1	mV	$V_{CE} = -5V, I_C = -2mA$
	0		4.5		
					$V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$
	C <sub>ibo</sub>		-		$V_{EB} = -0.5V$ , f = 1.0MHz, I <sub>C</sub> = 0
	h <sub>ie</sub>				
	h <sub>re</sub>	-	-	x 10⁴	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA,
	h <sub>fe</sub>	100	400	—	f = 1.0kHz
	h <sub>oe</sub>	3.0	60	μS	
	f <sub>T</sub>	250	_	MHz	V <sub>CE</sub> = -20V, I <sub>C</sub> = -10mA, f = 100MHz
	NF	_	4.0	dB	V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -100μA, R <sub>S</sub> = 1.0kΩ, f = 1.0kHz
				•	
	t <sub>d</sub>	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
	tr		35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$
			225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
		_	75	ns	$I_{B1} = I_{B2} = -1.0$ mA
	. ,	V(BR)EBO   ICEX   IBL   (Note 7)   hFE   (Note 7)   VCE(SAT)   (Note 7)   VBE(SAT)   ΔVBE   Cobo   Cibo   hie   hre   hfe   NF	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Notes: 6. 7.

Short duration pulse test used to minimize self-heating effect. The DC current gain,  $h_{FE}$ , (matched at  $I_C = -10$ mA and  $V_{CE} = -1.0$ V) Collector Emitter Saturation Voltage,  $V_{CE(SAT)}$ , and Base Emitter Saturation Voltage,  $V_{BE(SAT)}$  are matched with typical matched tolerances of 1% and maximum of 2%.







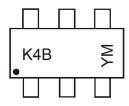


### Ordering Information (Note 8)

Device	Packaging	Shipping		
DMMT3906W-7-F	SOT-363	3000/Tape & Reel		

Notes: 8. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



K4B = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key												
Year	2002	2003	2004	200	5 20	06 2	007	2008	2009	2010	2011	2012
Code	N	Р	R	S	1	Г	U	V	W	Х	Y	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

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